Verilog Modeling of Transmission Line for USB 2.0 High-Speed PHY Interface

Ki-Hwan Seong, Ji-Hoon Lim, Byungsub Kim, Jae-Yoon Sim, and Hong-June Park

Abstract—A Verilog model is proposed for lines to perform the all-Verilog transmission simulation of high-speed chip-to-chip interface system, which reduces the simulation time by around 770 times compared to the mixed-mode simulation. The single-pulse response of transmission line in SPICE model is converted into that in Verilog model by converting the full-scale analog signal into an 11-bit digital code after uniform time sampling. The receiver waveform of transmission line is calculated by adding or subtracting the single-pulse response in Verilog model depending on the transmitting digital code values with appropriate time delay. The application of this work to a USB 2.0 high-speed PHY interface reduces the simulation time to less than three minutes with error less than 5% while the mixed-mode simulation takes more than two days for the same circuit.

Index Terms—Verilog, transmission line, USB 2.0 high-speed PHY, mixed-mode simulation

I. Introduction

The data rate of chip-to-chip interface is increased over several hundreds of Mbps or several Gbps recently, because of the ever-increasing requirement of databandwidth of electronic equipments. For the high-speed chip-to-chip interface, a transmission line is used to connect chips [1]. The circuit simulation is required to

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send out the designed chip for fabrication. For the circuit simulation the chip-to-chip interface system, the chips are described mostly in Verilog netlist and the transmission line is described in SPICE netlist. Therefore, a mixed-mode simulator such as SPECTRE is used for the simulation of chip-to-chip interface. It takes an excessively long time to perform the mixed-mode simulation of the circuit, which contains both Verilog and SPICE netlist, For example, it takes around two days to finish the mixed-mode simulation of a USB 2.0 highspeed interface for the time interval of 3us with a recent desktop PC. For the simulation of chip-to-chip interface, the MATLAB model [2] or the Verilog-AMS model [3, 4] were used. In the MATLAB model, the simulation time is much shorter than the mixed-mode simulator such as SPECTRE, since both transmission line and chip are modeled in MATLAB. However, because the chip is modeled usually in Verilog, it is inconvenient to convert the Verilog chip model to the MATLAB chip model. In the Verilog-AMS model, the Verilog chip model is used unchanged. However, the simulation time of the Verilog-AMS model is almost the same as the mixed-mode simulator such as SPECTRE, since the transmission line is described by the Verilog-A language in the Verilog-AMS model [5, 6].

In this work, to reduce the simulation time while keeping the Verilog chip model, the SPICE netlist of transmission line is converted into a Verilog netlist. This work takes less than three minutes to perform the abovementioned simulation of the USB 2.0 high-speed interface. Section II shows the procedure to convert the SPICE netlist of transmission line into a Verilog netlist. Section III presents the simulation results of this work for the USB 2.0 high-speed chip-to-chip interface. Section

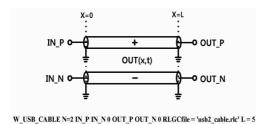


Fig. 1. A lossy differential transmission line.

IV concludes this work.

II. VERILOG OF TRANSMISSION LINE

1. SPICE Model of Transmission Line

A differential transmission line is mostly used for the serial-link chip-to-chip interface, such as USB, SATA, PCIe, MIPI, HDMI and Display Port.

The transmission line has a low-pass characteristic because of the dielectric loss and the skin effect loss. That is, the higher-frequency component is more severely attenuated by transmission line than the lower frequency component.

This phenomenon is modeled by a lossy transmission line model (W model) in SPICE. Fig. 1 shows the SPICE netlist of a differential lossy transmission line, where N=2 refers to the differential line. The 'usb2_cable.rlc' file contains the model parameter values of a lossy transmission line, which are represented by six 2-by-2 matrices shown in Fig. 2. Table 1 shows the values of the lossy transmission line parameters of Fig. 2 for a USB 2.0 cable.

If a differential input voltage of $\{+0.5 \exp(jwt), -0.5 \exp(jwt)\}$ is applied at the differential input nodes at x=0 (IN_P, IN_N) of Fig. 1, the differential voltage OUT(x, t) at a position x and a time t can be represented by

$$OUT(x,t) = e^{jw(t-L\sqrt{L_OC_O})}e^{-\alpha x}$$
 (1a)

$$\alpha = \frac{R_{skin}}{2\sqrt{L_O C_O}} + \frac{G_{dielectric}}{2\sqrt{L_O C_O}}$$
 (1b)

where no reflection is assumed because of the RX termination.

The attenuation constant alpha is determined by the skin effect parameter R_{skin} and the dielectric loss

$$\begin{split} L_O &= \begin{bmatrix} L_s & L_m \\ L_m & L_s \end{bmatrix} & R_O &= \begin{bmatrix} R_{os} & 0 \\ 0 & R_{os} \end{bmatrix} \\ \\ C_O &= \begin{bmatrix} C_s & C_m \\ C_m & C_s \end{bmatrix} & R_S &= \begin{bmatrix} R_{ss} & 0 \\ 0 & R_{ss} \end{bmatrix} \\ \\ G_O &= \begin{bmatrix} G_{os} & G_{om} \\ G_{om} & G_{os} \end{bmatrix} & G_d &= \begin{bmatrix} G_{ds} & G_{dm} \\ G_{dm} & G_{ds} \end{bmatrix} \end{split}$$

Fig. 2. Model parameter of a lossy differential transmission line.

parameter $G_{\text{dielectric.}} R_{\text{skin}}$ and $G_{\text{dielectric}}$ are represented by the lossy transmission line model parameters(R_o , R_s , G_o , G_d), which are included in the 'usb2_cable.rlc' file.

$$R_{skin} = R_O + R_S \sqrt{f} \tag{2a}$$

$$G_{dielecctric} = G_O + G_d f$$
 (2b)

2. Conversion of a Single-pulse Response from SPICE to Verilog

In this work, a SPICE single-pulse response PR(t) is calculated by using SPECTRE and then the SPICE single-pulse response is converted into a Verilog singlepulse response D PR(t). D PR(t) is used to get the received waveform at RX for any digital data transmitted at TX. To get the SPICE single-pulse response PR(t), the SPECTRE [7] simulation is performed for the SPICE model part enclosed by the dashed line shown in Fig. 3(a), which includes the chip pin parasitic and the transmission lines. The TX driver is assumed to be an ideal CML driver, and the RX front-end consists of an ideal differential comparator. For this, a single current pulse is applied to IINP(t) of Fig. 3(a) while IINN(t) remains at zero, as shown in Fig. 4. Then, the RX input waveform VRX(t) from SPECTRE simulation is converted into a SPICE single-pulse response PR(t) by eliminating the transmission line delay (time of flight tF), as shown in Fig. 5. T is an input data period. That is,

$$PR(t) = V_{RX}(t + t_F) \tag{3}$$

While the non-zero response starts from t = tF in

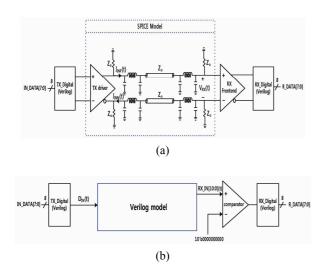


Fig. 3. (a) SPICE model, (b) Verilog model of transmission line.

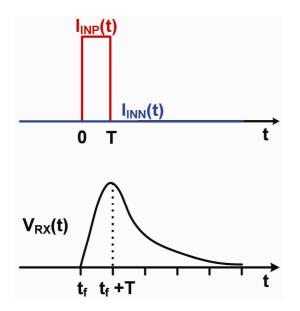


Fig. 4. Input and output waveforms of the SPICE model (Fig. 3(a)).

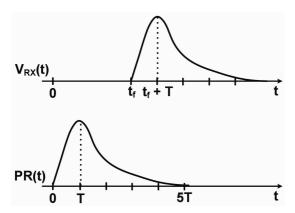


Fig. 5. Derivation of a SPICE single-pulse response PR(t) from $V_{RX}(t)$.

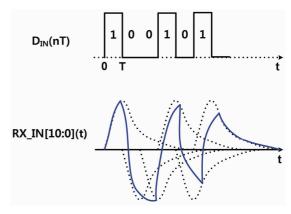


Fig. 6. Superposition of a Verilog single-pulse response $(D_PR(t))$ to find the receiver input waveform RX_IN[10:0](t) for the TX digital output $(D_{IN}(nT))$.

VRX(t), it starts from t = 0 in PR(t). This SPICE singlepulse response PR(t) is sampled in uniform time steps and the sampled values are stored as the Verilog singlepulse response D_PR(t) for a few data periods.

3. Verilog Model of Transmission Line

The SPICE model part of Fig. 3(a) is converted into a Verilog model, as shown in Fig. 3(b). The SPICE model part includes the transmission line, the CML driver, and the parasitic components. Also, the analog differential comparator of Fig. 3(a) is converted into the digital comparator of Fig. 3(b). In this way, all the components in the chip-to-chip interface are described entirely in Verilog. The Verilog single-pulse response D_PR(t) is used to get the receiver input waveform RX_IN(t) at RX for any digital data DIN(nT) transmitted at TX. At every data period of t=nT, either a positive or negative single-pulse response (+ D_PR(t) or – D_PR(t)) is delayed by nT and added to RX_IN(t) for the TX digital data DIN(nT) of 1 or 0, respectively. This can be expressed as

$$RX_{IN}[10:0](t) = \sum_{n=0}^{\infty} PR(t-nT)\{2*DIN(ntT)-0.5\}$$
(4)

This superposition of single-pulse response can be performed since the transmission line is a linear-time-invariant(LTI) system. The Verilog single-pulse response D_PR(t) corresponds to an impulse response of LTI system, as can be seen in Eq. (4). Eq. (4) is a convolution function. Fig. 6 shows how to find the RX_IN(t)

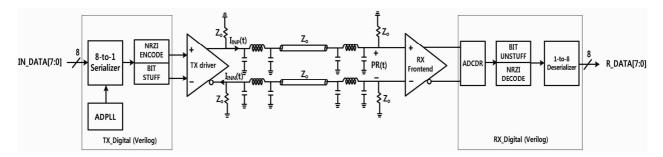


Fig. 7. Chip-to-chip interface through a USB 2.0 high-speed PHY [9].

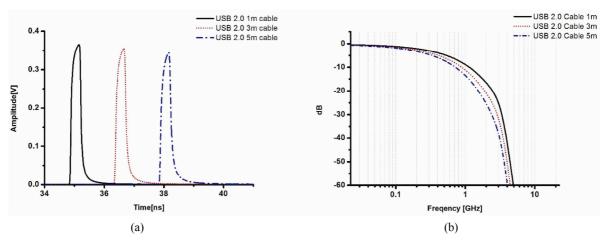


Fig. 8. A transient pulse response (a) and a frequency magnitude response, (b) of USB 2.0 cable.

waveform by the linear superposition for the TX output data of '100101'.

III. APPLICATION TO USB 2.0 HIGH-SPEED PHY SIMULATION

1. Verilog Model of USB 2.0 Cable

The proposed Verilog model of transmission line is applied to the USB 2.0 high-speed PHY simulation. Two USB 2.0 high-speed PHY chips (TX_Digital and RX_Digital) are connected through a USB cable, as shown in Fig. 7. Both TX_Digital and RX_Digital blocks are described entirely in Verilog. The transmission line part is also described in Verilog by using the method proposed in this work.

To find the SPICE single-pulse response PR(t) of a USB 2.0 cable by using SPECTRE, a lossy transmission line is used. The parameters of lossy transmission line model (W model), which are included in the RLGC file, are shown in Table 1. A π -shaped pin parasitic model

with a 3nH inductor and two 1.5pF capacitors is also included in the USB cable model. For three USB 2.0 cables with different lengths(1m, 3m, 5m), a transient SPECTRE simulation is performed to find PR(t). A single current pulse of 18mA is applied to I_{INP}(t) of transmitter (Fig. 3(a)) during one data period of 500Mbps. The analog PR(t) waveforms for the three USB cables are shown in Fig. 8(a), where t_{F1} , t_{F2} , and t_{F3} are the times of flight of each USB cable. Also, the frequency responses of USB cables are presented in Fig. 8(b). The digital D_PR(t) waveform is stored in a file named 'Single Pulse Response.txt' in a 11-bit resolution, starting from t = 0until t = 5T in ten ps steps. T is a data period(2ns) of 500Mbps. Only five data periods are stored for D PR(t) since the ISI component of a singlepulse response is negligible after five data periods, as shown in Fig. 8(a).

The Verilog code to calculate the 11-bit receiver input waveform RX_IN[10:0](t) by using (4) is presented in Fig. 9. Only five preceding data values including the current one are used for the RX_IN computation. The RX_IN[10:0](t) output from the Verilog code is shifted

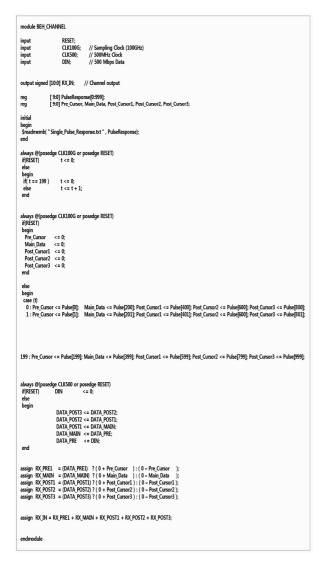


Fig. 9. Verilog model for USB 2.0 Cable.

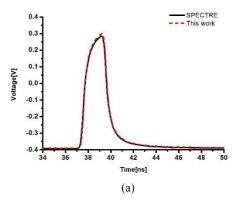
Table 1. W model parameters of USB 2.0 cable

Parameters	L _s [H/m]	L _m [H/m]	C _s [F/m]	C _m [F/m]
Values	2.03 X 10 ⁻⁷	1.68 X 10 ⁻⁸	9.96 X 10 ⁻¹¹	-5.18 X 10 ⁻¹²
Parameters	$R_{os}[\Omega/m]$	$R_{ss}[\Omega/m]$	$G_{ds}[\Omega^{-1}/m]$	$G_{dm}[\Omega^{-1}/m]$
Values	2.81 X 10 ⁻¹	2.53 X 10 ⁻⁴	2.08 X 10 ⁻¹¹	-8.81 X 10 ⁻¹³

by t_F in time axis for the final result.

2. Comparison of this work with SPECTRE simulation

To verify the validity of this work, a single-pulse response of receiver input waveform is compared between this work and SPECTRE. Excellent agreements



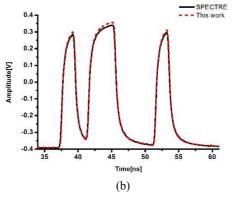


Fig. 10. Comparison between this work and SPECTRE with 5m USB 2.0 cable (a) single-pulse response, (b) response to '1011000100' input.

can be observed with the maximum relative error of 4.05% as shown in Fig. 10(a).

To simulate the real environment, the input data(IN DATA[7:0]) stream of Fig. 7 is extracted by applying a USB protocol analyzer to a real USB 2.0 high-speed interface between a memory stick and PC, starting from the plug-in time until the memory stick device is recognized by PC after the device configuration stage is completed [8]. It takes around 3us in a real USB 2.0 high-speed interface. The extracted IN DATA[7:0] stream for the entire 3us interval is applied both to the Verilog model(Fig. 3(a)) of this work and SPECTRE (Fig. 3(a)). The data rate of 500Mbps with a 5m USB 2.0 cable is used in this simulation. The eye patterns from this simulation are compared in Fig. 11, which shows excellent agreements. The receiver output data(OUT DATA[7:0] of Fig. 7) are obtained from Verilog simulation of this work, and are presented in Fig. 12 for the very initial part of the 3us simulation. Exact matches can be found between the TX input data(IN DATA[7:0]) and the RX output data. The simulation statistics are

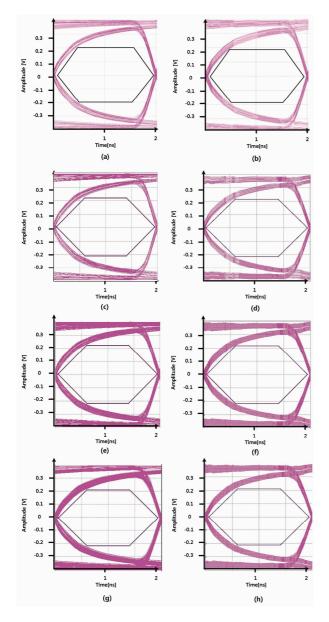


Fig. 11. Comparison of eye patterns (a) SPECTRE, (b) this work of USB 2.0 Descriptor, (c) SPECTRE, (d) this work of 2⁷-1 test pattern, (e) SPECTRE, (f) this work of 2¹⁵-1 test pattern, (g) SPECTRE, (h) this work of 2³¹-1 test pattern.



Fig. 12. Received digital output code (OUT_DATA[7:0]) from simulation of this work.

compared in Tables 2 and 3. This work is faster than SPECTRE by around 770 times.

Table 2. Comparison of simulation statistics between this work and SPECTRE

	SPECTRE	This work	
TX, RX netlist	Verilog	Verilog	
TL netlist	SPICE	Verilog	
Total simulation time[sec]	126,000	163	
#Time point	30,000	30,000	

Table 3. Comparison of simulation statistics between this work and SPECTRE of USB 2.0 Descriptor, PRBS 2⁷-1, 2¹⁵-1 and 2³¹-1 Test pattern

Channel	Test Pattern	Voltage Opening		Time Opening	
		SPETRE	This work	SPETRE	This work
USB 2.0 5m Cable	USB 2.0 Descriptor	66.5%	66.5%	97%	97%
	2 ⁷ -1 PRBS	68.75%	68.73%	97.5%	97.5%
	215-1 PRBS	67.5%	67.1%	97.5%	97.2%
	2 ³¹ -1 PRBS	66.5%	66.5%	97%	97%

IV. CONCLUSIONS

The SPICE netlist of transmission line is converted into a Verilog model in the chip-to-chip USB 2.0 high-speed PHY interface to reduce the simulation time by around 770 times compared to the SPECTRE mixed-mode simulation. It takes less than 3 minutes to simulate the entire period(~3us) of device configuration stage of USB 2.0 high-speed interface, while it takes more than 2 days with SPECTRE. The USB 2.0 interface circuit used in this work consists of a TX digital part, a USB 2.0 cable and a RX digital part.

Both the TX and the RX digital parts are modeled in Verilog for both this work and SPECTRE. The USB 2.0 cable is modeled in Verilog for this work and in SPICE netlist for SPECTRE. A single-pulse response of five data periods is calculated by SPECTRE and stored in a file. The stored single-pulse response is linearly added or subtracted with appropriate delays to calculate the receiver input waveform depending on the TX data values. The receiver input waveform is represented in a 11-bit digital code. Excellent agreements are observed between this work and SPECTRE in waveforms, eye patterns and code values.

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